P3CD05170P

1700V/5A SiC Power Schottky Barrier Diode Product

PowerCubeSemi, Inc.
Potential · Convergence · Smart

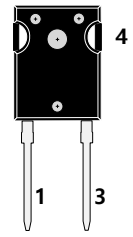
Features

- Positive temperature coefficient for easy parallel use
- Switching characteristics that are not affected by temperature
- Maximum operating temperature 175 ° C
- Zero reverse recovery current
- Zero forward recovery voltage

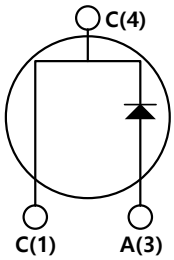
Key Characteristics		
V_{RRM}	1700	V
$I_F, T_C \leq 160℃$	5	A
Q_C	65	nC

Benefits

- Unipolar device
- Greatly reduce switching losses
- No thermal crash in parallel devices
- Reduce system dependence on heat sinks



PKG : TO-247



Applications

- Switch Mode Power Supply (SMPS), Power Factor Correction (PFC)
- Motor drive, photovoltaic inverter, uninterruptible power supply, Wind turbines, train traction systems, electric vehicles.

Halogen-Free

RoHS

Absolute Maximum Ratings T_C = 25℃ unless otherwise specified

Symbol	Parameter	Test Condition	Value	Unit
V_{RRM}	Repetitive Peak Reverse Voltage		1700	V
V_{RSM}	Surge Peak Reverse Voltage		1700	V
V_{DC}	DC Blocking Voltage		1700	V
I_F	Continuous Forward Current	T_C=25℃	24	A
		T_C=135℃	12	A
		T_C=160℃	5	A
I_{FRM}	Repetitive Peak Forward Surge Current	T_C=25℃, tp=10ms, Half Sine Wave, D=0.3	25	A
I_{FSM}	Non-repetitive Peak Forward Surge Current	T_C=25℃, tp=10ms, Half Sine Wave	120	A
P_{TOT}	Power Dissipation	T_C=25℃	142	W
		T_C=110℃	61	
T_j	Operating Junction		-55 to 175	℃
T_{stg}	Storage Temperature		-55 to 175	℃

Thermal Characteristics

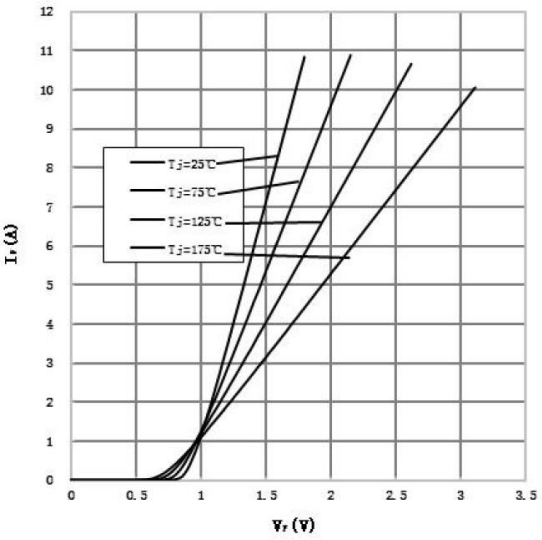
Symbol	Parameter	Test Condition	Value	Unit
			Typ.	
R_{thJc}	Thermal resistance from junction to case		1.06	℃/W

Electrical Characteristics, Nomination temperature Tj=25°C

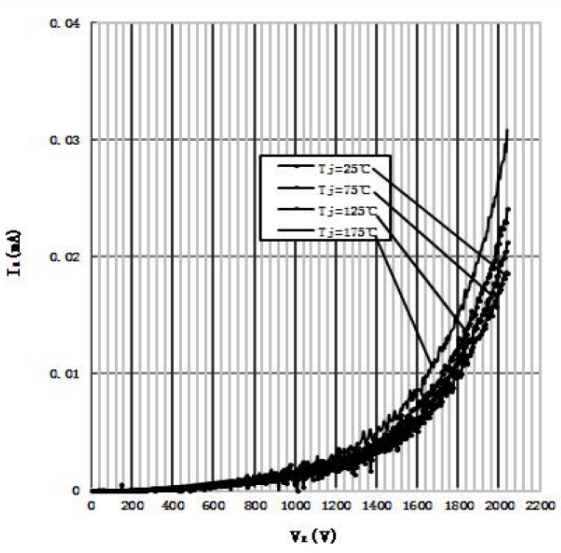
Symbol	Parameter	Test Condition	Numerical		Unit
			Typ.	Max.	
V_F	Forward Voltage	I_F=5A, T_j=25℃	1.4	1.7	V
		I_F=5A, T_j=175℃	2	2.5	
I_R	Reverse Current	V_R=1700V, T_j=25℃	10	50	μA
		V_R=1700V, T_j=175℃	20	100	
Q_C	Total capacitive Charge	V_R=1200V, T_j=150℃ $Qc = \int_0^{VR} C(V)dV$	65	-	nC
C	Total Capacitance	V_R=0V, T_j=25℃, f=1MHZ	780	800	pF
		V_R=400V, T_j=25℃, f=1MHZ	48	50	
		V_R=800V, T_j=25℃, f=1MHZ	34.5	35	

Performance Graphs

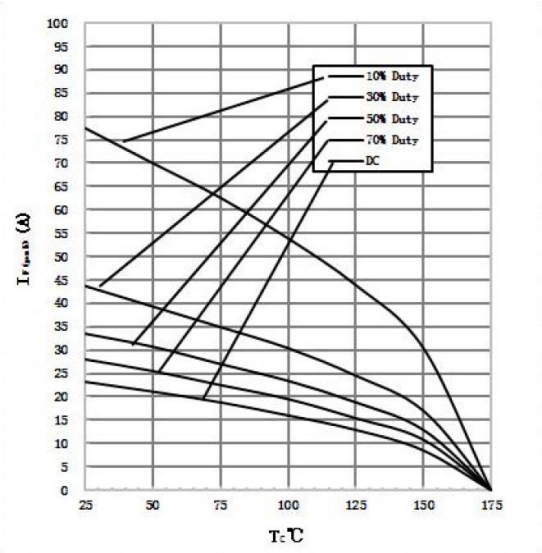
1)Forward IV characteristics as a function of T_j



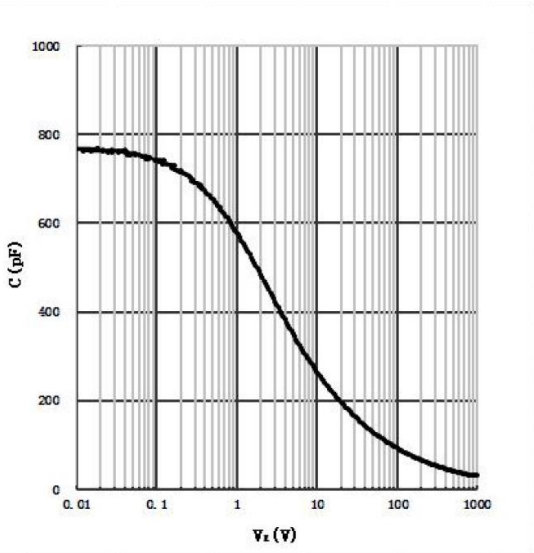
2)Reverse IV characteristics as a function of T_j



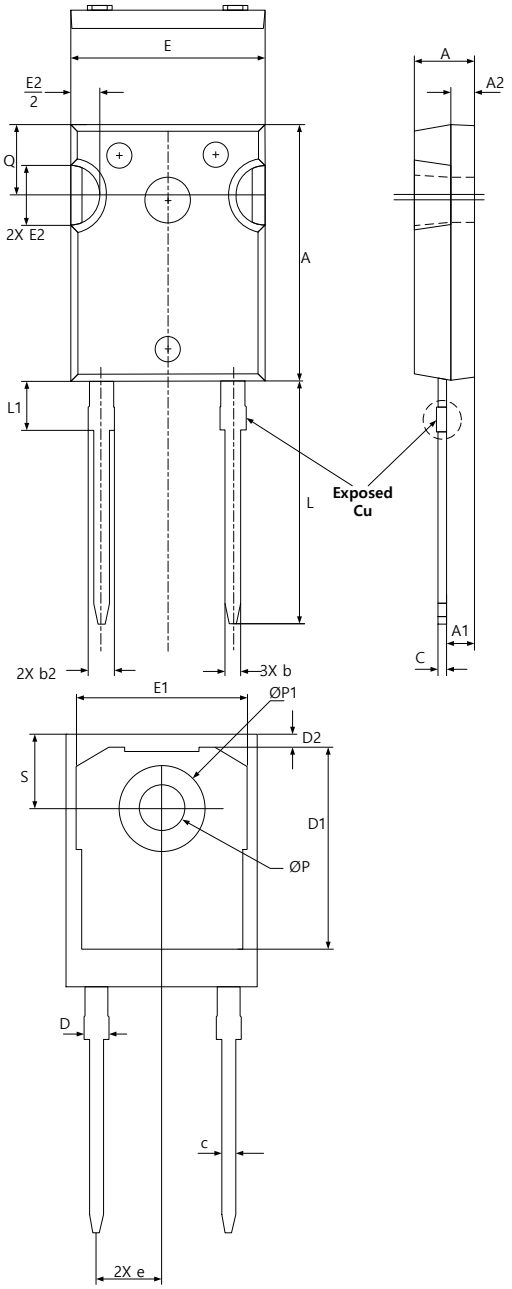
3)Current Derating



4)Capacitance VS. reverse voltage



Package Outline



SYMBOL	DIMENSIONS			NOTES
	MIN	NOM	MAX	
A	4.83	5.02	5.21	
A1	2.29	2.41	2.55	
A2	1.50	2.00	2.49	
B	1.12	1.20	1.33	
B1	1.12	1.20	1.28	
B2	1.91	2.00	2.39	6
B3	1.91	2.00	2.34	
C	0.55	0.60	0.69	6
C1	0.55	0.60	0.65	
D	20.80	20.95	21.10	4
D1	16.25	16.55	17.65	5
D2	0.51	1.19	1.35	
E	15.75	15.94	16.13	4
E1	13.46	14.02	14.16	5
E2	4.32	4.91	5.49	3
e	5.44BSC			
L	19.81	20.07	20.32	
L1	4.10	4.19	4.40	6
ϕP	3.56	3.61	3.65	7
ϕP1	7.19REF			
Q	5.39	5.79	6.20	
S	6.04	6.17	6.30	

Symbol	Parameter	Test Condition	Numerical		Unit
			Typ.	Max.	
M_d	Mounting torque	TO-247 M3 Screw 6-32 Screw	1/8.8	-	Nm/lbf.in.